### imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



### Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



PRELIMINARY SPEC

#### 3.0mmx1.0mm RIGHT ANGLE PHOTOTRANSISTOR

Part Number: APA3010P3BT

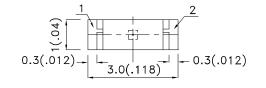
#### **Features**

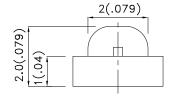
- 3.0mmx1.0mm RIGHT ANGLE SMT LED, 2.0mm THICKNESS.
- MECHANICALLY AND SPECTRALLY MATCHED TO THE INFRARED EMITTING LED LAMP.
- BLUE TRANSPARENT LENS.
- PACKAGE : 2000PCS / REEL.
- MOISTURE SENSITIVITY LEVEL : LEVEL 3.
- RoHS COMPLIANT.

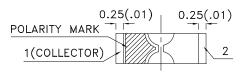
Description

Made with NPN silicon phototansistor chips.

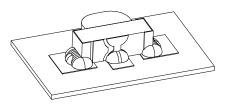
**Package Dimensions** 







2



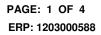
Notes:

1. All dimensions are in millimeters (inches).

2. Tolerance is ±0.15(0.006") unless otherwise noted.

Specifications are subject to change without notice.
The device has a single mounting surface. The device must be mounted according to the specifications.

DATE: JAN/10/2008 **DRAWN: R.Chen** 



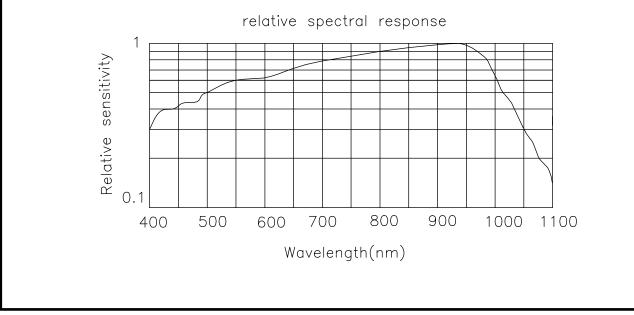
### Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
VBR CEO	Collector-to-Emitter Breakdown Voltage	30			v	Ic=100uA Ee=0mW/c mໍ
VBR ECO	Emitter-to-Collector Breakdown Voltage	5			v	l∈=100uA Ee=0mW/c mঁ
VCE (SAT)	Collector-to-Emitter Saturation Voltage			0.8	v	lc=2mA Ee=20mW/c m <sup>³</sup>
I ceo	Collector Dark Current			100	nA	Vce=10V Ee=0mW/c mឺ
Tr	Rise Time (10% to 90% $)$		15		us	Vce = 5V Ic=1mA RL=1000Ω
TF	Fall Time (90% to 10% )		15		us	
l (on)	On State Collector Current	0.2	0.8		mA	Vce = 5V Ee=1mW/c m <sup>³</sup> λ=940nm
201/2	Viewing Angle		110		deg	

#### Absolute Maximum Ratings at TA=25°C

Parameter	Max.Ratings		
Collector-to-Emitter Voltage	30V		
Emitter-to-Collector Voltage	5V		
Power Dissipation at (or below) 25°C Free Air Temperature	100mW		
Operating Temperature	-40°C To +85°C		
Storage Temperature	-40°C To +85°C		

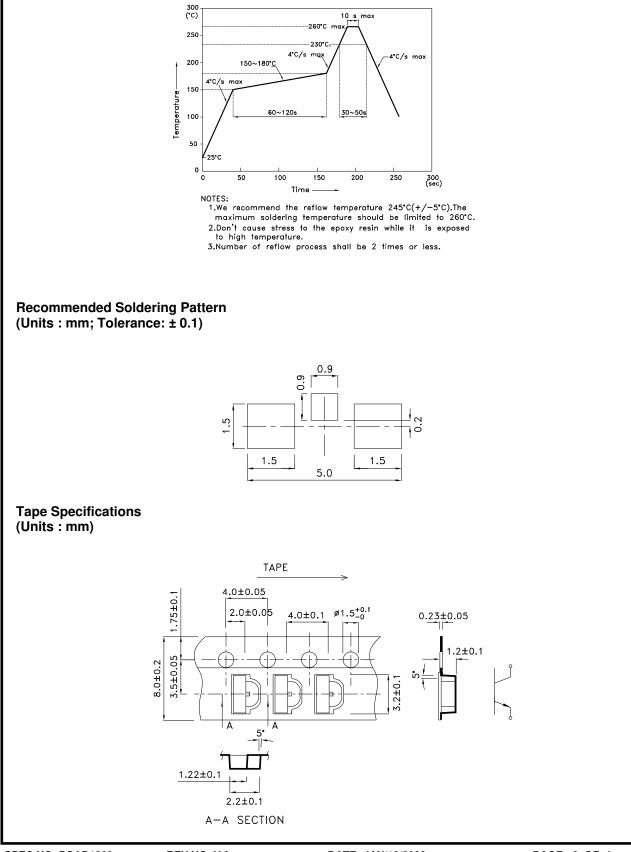
#### APA3010P3BT



DATE: JAN/10/2008 DRAWN: R.Chen



Reflow Soldering Profile For Lead-free SMT Process.



REV NO: V.8 CHECKED: Allen Liu DATE: JAN/10/2008 DRAWN: R.Chen PAGE: 3 OF 4 ERP: 1203000588

